NSN 5962-01-369-9256

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View Online at https://aerobasegroup.com/nsn/5962-01-369-9256

Body Length: 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.1 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and programmed and high impedance and w/enable and w/disable and electrostatic sensitive and w/clock **Inclosure Material:** Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

9 input

Case Outline Source And Designator:

D-8 mil-m-38510

Current Rating Per Characteristic:

180.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Registered and-or gate array

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 12.0 volts power source

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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